Product data sheet

1. General description

Standard reverse recovery power diode in a TO263 package.





2. Features and benefits

- · Low forward voltage drop
- Low leakage current
- · High voltage capability
- · High inrush current capability

3. Applications

- · Oring diode
- Bypass diode
- · Input rectifier for bridge configurations

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit		
Absolute	Absolute maximum rating								
V_{RRM}	repetitive peak reverse voltage				1600		V		
$I_{F(AV)}$	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 97$ °C; Fig. 1; Fig. 2; Fig. 3			35		Α		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		400			Α		
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		435 A			А		
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit		
Static ch	Static characteristics								
V _F	forward voltage	I _F = 35 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.18	1.40	V		
I _R	reverse current	V _R = 1600 V; T _j = 25 °C		-	-	50	μΑ		

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Α	anode		K — A
2	К	cathode [1]		001aaa020
3	Α	anode		
mb	К	mounting base; connected to cathod	1 3 TO-263 (D2PAK)	

^[1] It is not possible to connect to pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WND35P16B	TO263	WND35P16BJ	Reel	800	TO263N	26-Sep-2016

7. Marking

Table 4. Marking codes

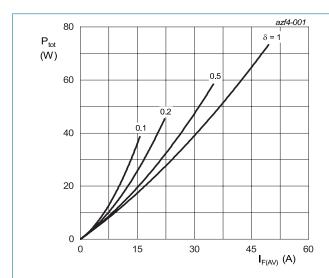
Type number	Marking codes
WND35P16B	WND35P16B

8. Limiting values

Table 5. Limiting values

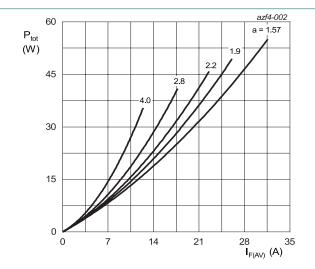
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			1600	V
V_{RWM}	crest working reverse voltage			1600	V
V_R	reverse voltage	DC		1600	V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 97$ °C; Fig. 1; Fig. 2; Fig. 3		35	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		400	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		435	А
l²t	I ² t for fusing	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		800	A ² s
T _{stg}	storage temperature			-40 to 150	°C
T _j	junction temperature			-40 to 150	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.025 \text{ V}; \text{ R}_s = 0.0092 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}$ / $I_{F(AV)}$ V_o = 1.025 V; R_s = 0.0092 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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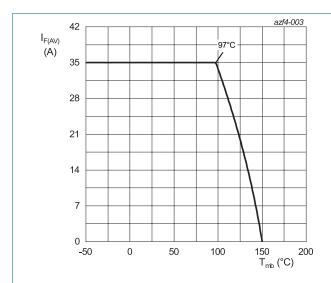


Fig. 3. Forward current as a function of mounting base temperature; maximum values

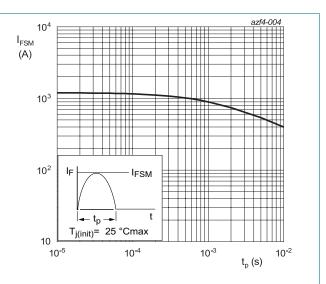


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Values	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	0.9	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W

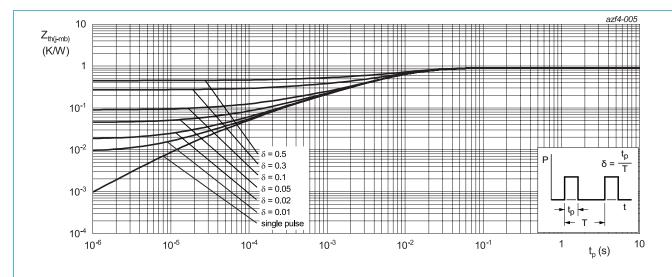
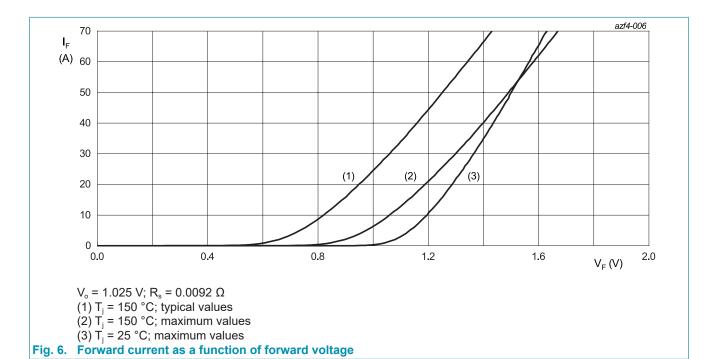


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

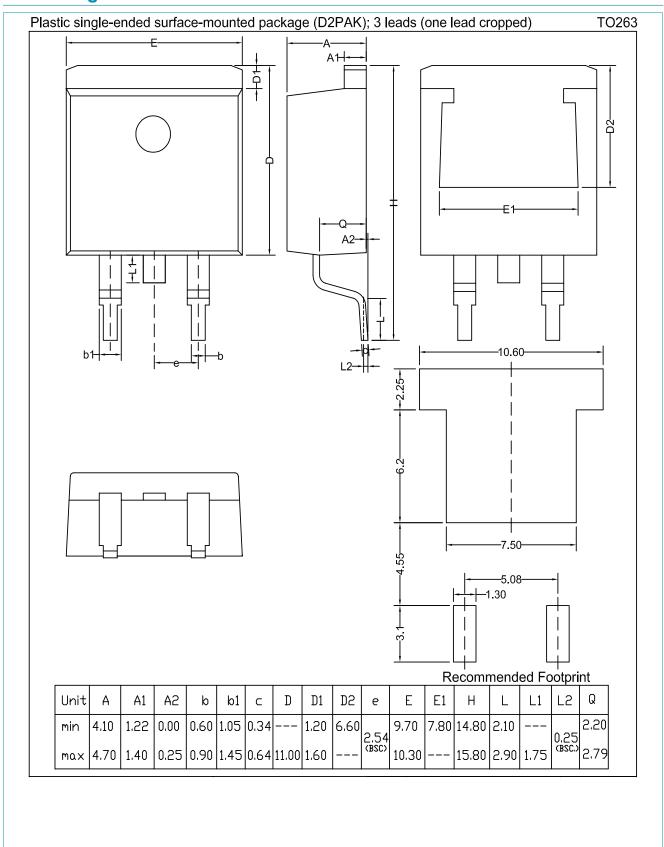
10. Characteristics

Table 7. Characteristics

10010 11 01	14140101101100						
Symbol	Parameter	Conditions	Notes	Values	Тур	Max	Unit
Static cha	racteristics						
V_{F}	forward current	I _F = 35 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.18	1.40	V
		I _F = 35 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.15	1.35	V
		I _F = 25 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.10	1.30	V
		I _F = 25 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.05	1.25	V
I _R reverse current		V _R = 1600 V; T _j = 25 °C		-	-	50	μΑ
		V _R = 1600 V; T _j = 150 °C		-	-	1	mA



11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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